

NTD70N03R

Power MOSFET

72 A, 25 V, N-Channel DPAK

Features

- Planar HD3e Process for Fast Switching Performance
- Low $R_{DS(on)}$ to Minimize Conduction Loss
- Low C_{ISS} to Minimize Driver Loss
- Low Gate Charge
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ Unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DS}	25	V_{dc}
Gate-to-Source Voltage - Continuous	V_{GS}	± 20	V_{dc}
Thermal Resistance - Junction-to-Case	$R_{\theta JC}$	2.4	$^\circ\text{C/W}$
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	P_D	62.5	W
Drain Current			
- Continuous @ $T_C = 25^\circ\text{C}$, Chip	I_D	72.0	A
- Continuous @ $T_C = 25^\circ\text{C}$, Limited by Package	I_D	62.8	A
- Continuous @ $T_A = 25^\circ\text{C}$, Limited by Wires	I_D	32	A
- Single Pulse ($t_p = 10 \mu\text{s}$)	I_{DM}	140	A
Thermal Resistance - Junction-to-Ambient (Note 1)	$R_{\theta JA}$	80	$^\circ\text{C/W}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	1.87	W
Drain Current - Continuous @ $T_A = 25^\circ\text{C}$	I_D	12.0	A
Thermal Resistance - Junction-to-Ambient (Note 2)	$R_{\theta JA}$	110	$^\circ\text{C/W}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	1.36	W
Drain Current - Continuous @ $T_A = 25^\circ\text{C}$	I_D	10.0	A
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 175	$^\circ\text{C}$
Single Pulse Drain-to-Source Avalanche Energy - Starting $T_J = 25^\circ\text{C}$ ($V_{DD} = 30 V_{dc}$, $V_{GS} = 10 V_{dc}$, $I_L = 12 A_{pk}$, $L = 1 \text{ mH}$, $R_G = 25 \Omega$)	E_{AS}	71.7	mJ
Maximum Lead Temperature for Soldering Purposes, 1/8" from Case for 10 s	T_L	260	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

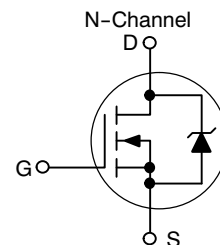
1. When surface mounted to an FR4 board using 0.5 sq. in. pad size.
2. When surface mounted to an FR4 board using minimum recommended pad size.



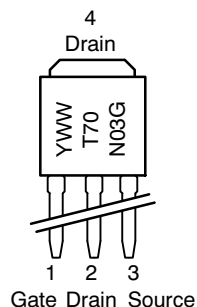
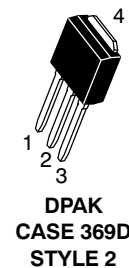
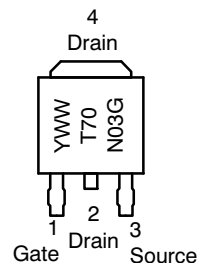
ON Semiconductor®

<http://onsemi.com>

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D MAX
25 V	5.6 m Ω	72 A



MARKING DIAGRAMS



70N03 = Device Code
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NTD70N03R

ELECTRICAL CHARACTERISTICS (T_J = 25°C Unless otherwise specified)

Characteristics	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (Note 3) (V _{GS} = 0 V _{dc} , I _D = 250 μA _{dc}) Temperature Coefficient (Positive)	V _{(br)DSS}	25 –	28 20.5	– –	V _{dc} mV/°C
Zero Gate Voltage Drain Current (V _{DS} = 20 V _{dc} , V _{GS} = 0 V _{dc}) (V _{DS} = 20 V _{dc} , V _{GS} = 0 V _{dc} , T _J = 150°C)	I _{DSS}	– –	– –	1.5 10	μA _{dc}
Gate-Body Leakage Current (V _{GS} = ±20 V _{dc} , V _{DS} = 0 V _{dc})	I _{GSS}	–	–	±100	nA _{dc}

ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage (Note 3) (V _{DS} = V _{GS} , I _D = 250 μA _{dc}) Threshold Temperature Coefficient (Negative)	V _{GS(th)}	1.0 –	1.5 4.0	2.0 –	V _{dc} mV/°C
Static Drain-to-Source On-Resistance (Note 3) (V _{GS} = 4.5 V _{dc} , I _D = 20 A _{dc}) (V _{GS} = 10 V _{dc} , I _D = 20 A _{dc})	R _{DS(on)}	– –	8.1 5.6	13 8.0	mΩ
Forward Transconductance (Note 3) (V _{DS} = 10 V _{dc} , I _D = 15 A _{dc})	g _{FS}	–	27	–	Mhos

DYNAMIC CHARACTERISTICS

Input Capacitance	(V _{DS} = 20 V _{dc} , V _{GS} = 0 V, f = 1 MHz)	C _{ISS}	–	1333	–	pF
Output Capacitance		C _{OSS}	–	600	–	
Transfer Capacitance		C _{RSS}	–	218	–	

SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	(V _{GS} = 10 V _{dc} , V _{DD} = 10 V _{dc} , I _D = 36 A _{dc} , R _G = 3 Ω)	t _{d(on)}	–	6.9	–	ns
Rise Time		t _r	–	1.3	–	
Turn-Off Delay Time		t _{d(off)}	–	18.4	–	
Fall Time		t _f	–	5.5	–	
Gate Charge	(V _{GS} = 5 V _{dc} , I _D = 36 A _{dc} , V _{DS} = 10 V _{dc}) (Note 3)	Q _T	–	13.2	–	nC
		Q _{GS}	–	3.3	–	
		Q _{DS}	–	6.5	–	

SOURCE-DRAIN DIODE CHARACTERISTICS

Forward On-Voltage	(I _S = 20 A _{dc} , V _{GS} = 0 V _{dc}) (Note 3) (I _S = 20 A _{dc} , V _{GS} = 0 V _{dc} , T _J = 125°C)	V _{SD}	– –	0.86 0.73	1.2 –	V _{dc}
Reverse Recovery Time	(I _S = 36 A _{dc} , V _{GS} = 0 V _{dc} , dI _S /dt = 100 A/μs) (Note 3)	t _{rr}	–	27.9	–	ns
		t _a	–	14.8	–	
		t _b	–	13.1	–	
Reverse Recovery Stored Charge		Q _{RR}	–	19	–	nC

3. Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.

4. Switching characteristics are independent of operating junction temperatures.

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TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

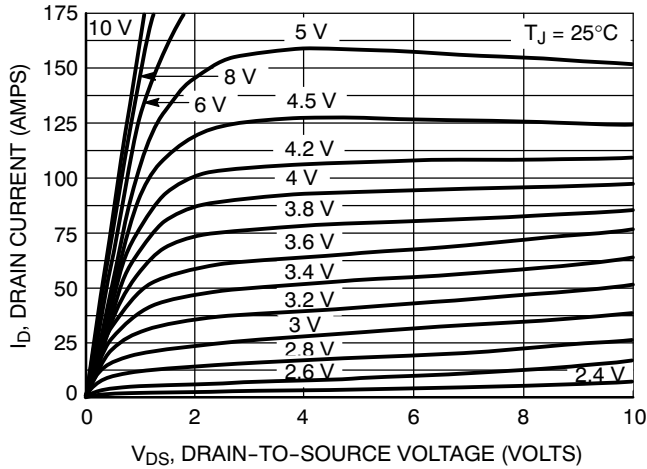


Figure 1. On-Region Characteristics

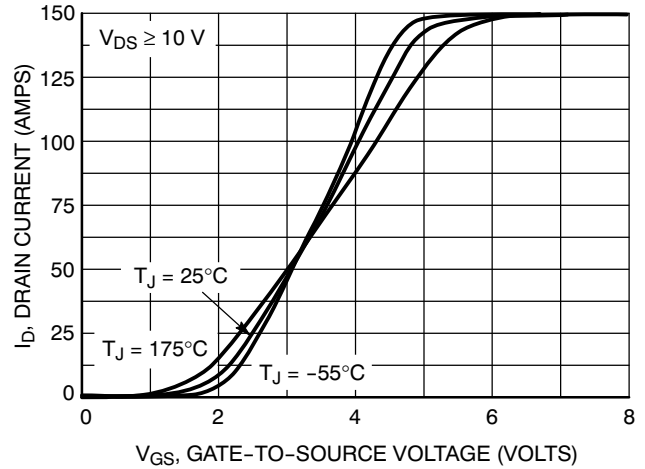


Figure 2. Transfer Characteristics

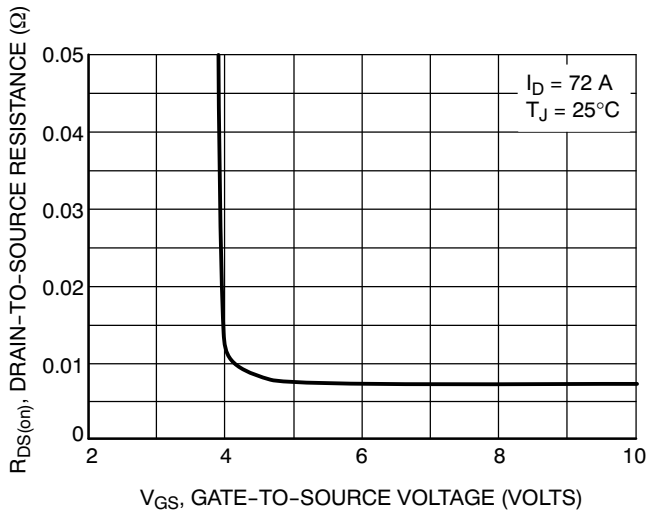


Figure 3. On-Resistance versus Gate-to-Source Voltage

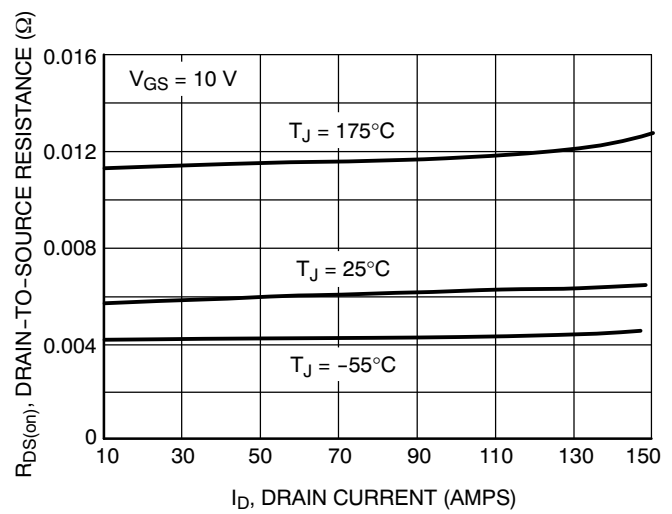


Figure 4. On-Resistance versus Drain Current and Gate Voltage

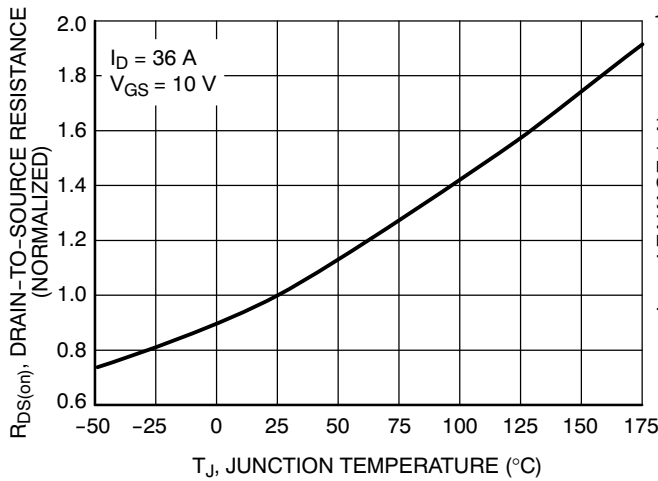


Figure 5. On-Resistance Variation with Temperature

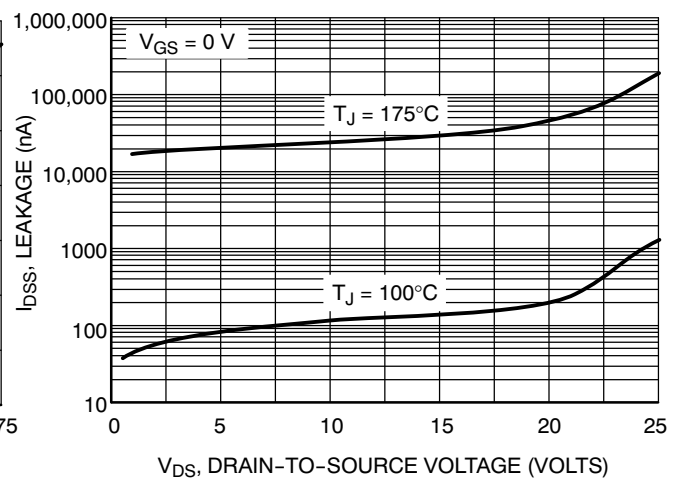


Figure 6. Drain-to-Source Leakage Current versus Voltage

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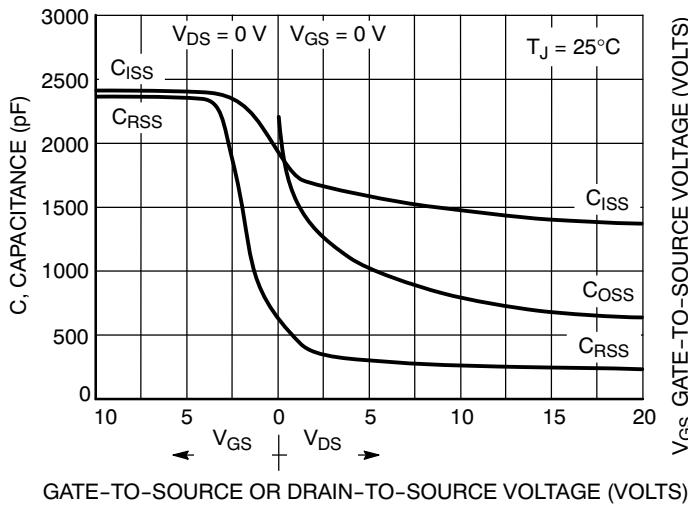


Figure 7. Capacitance Variation

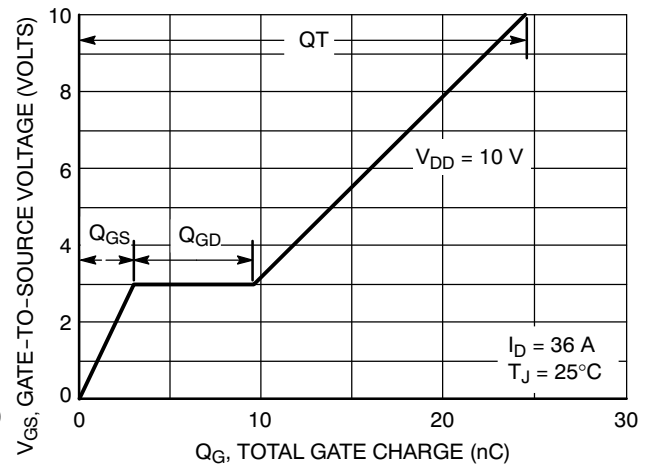


Figure 8. Gate-To-Source and Drain-To-Source Voltage versus Total Charge

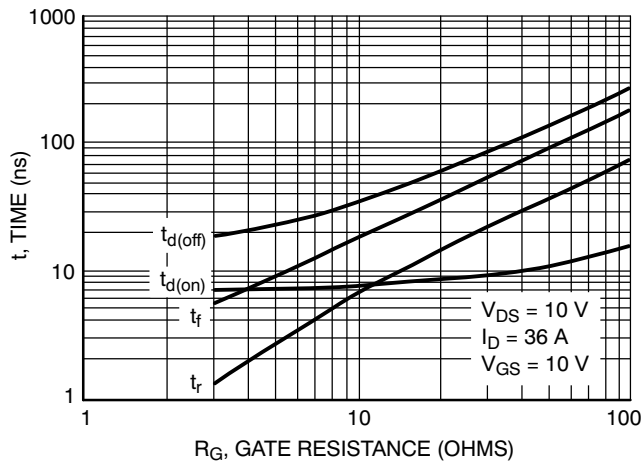


Figure 9. Resistive Switching Time Variation versus Gate Resistance

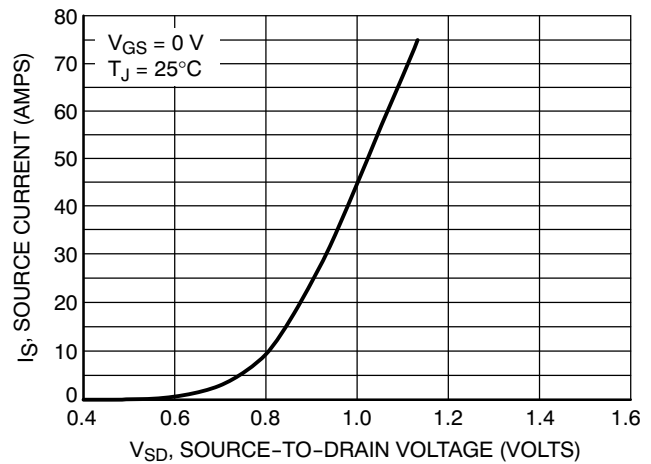


Figure 10. Diode Forward Voltage versus Current

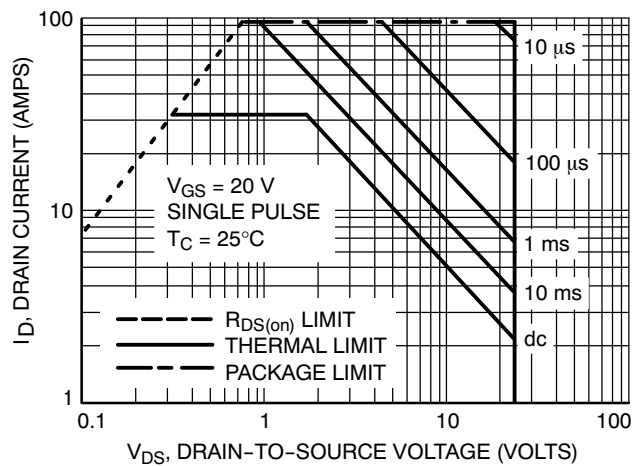


Figure 11. Maximum Rated Forward Biased Safe Operating Area

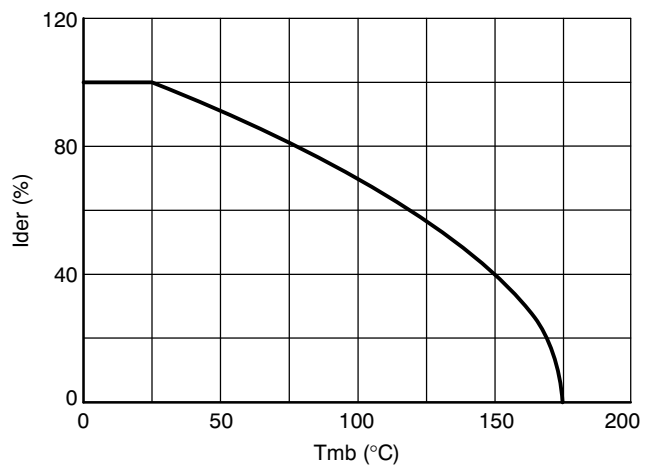


Figure 12. Normalized Continuous Drain Current as a function of Mounting Base Temperature

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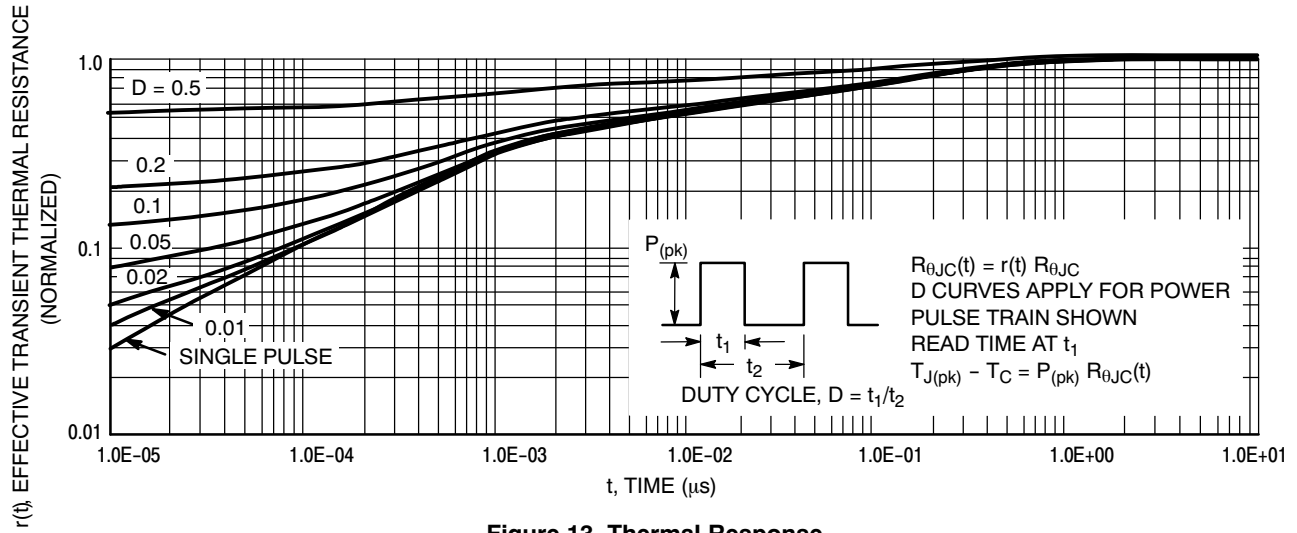


Figure 13. Thermal Response

ORDERING INFORMATION

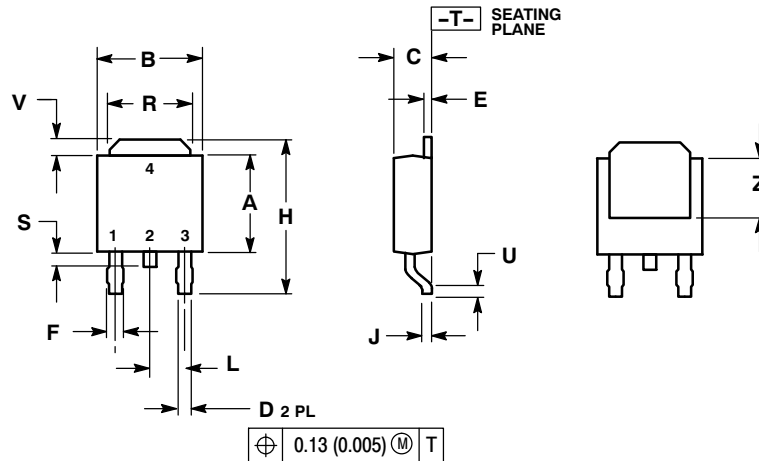
Order Number	Package	Shipping [†]
NTD70N03R	DPAK-3	75 Units / Rail
NTD70N03RG	DPAK-3 (Pb-Free)	75 Units / Rail
NTD70N03RT4	DPAK-3	2500 / Tape & Reel
NTD70N03RT4G	DPAK-3 (Pb-Free)	2500 / Tape & Reel
NTD70N03R-1	DPAK-3 Straight Lead	75 Units / Rail
NTD70N03R-1G	DPAK-3 Straight Lead (Pb-Free)	75 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

DPAK
CASE 369AA-01
ISSUE A

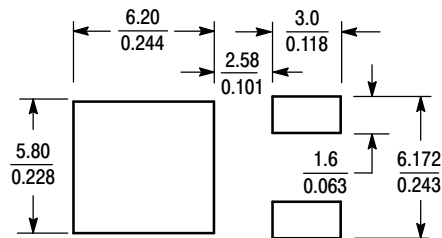


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.025	0.035	0.63	0.89
E	0.018	0.024	0.46	0.61
F	0.030	0.045	0.77	1.14
H	0.386	0.410	9.80	10.40
J	0.018	0.023	0.46	0.58
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.024	0.040	0.60	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

- STYLE 2:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

SOLDERING FOOTPRINT*



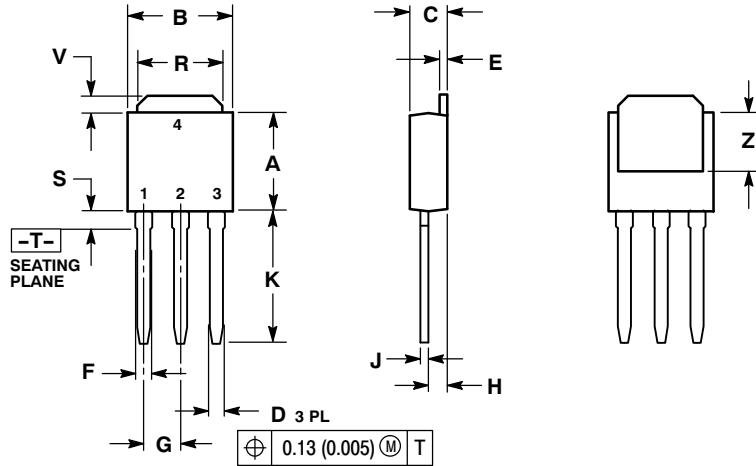
SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PACKAGE DIMENSIONS

DPAK CASE 369D-01 ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29	BSC
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

STYLE 2:

- PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

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